1. General description

Double NPN switching transistor in an ultra small DFN1412-6 (SOT1268) leadless Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Leadless ultra small SMD plastic package
- · Reduces component count
- · Reduces pick and place costs
- Low package height of 0.5 mm

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V _{CEO}	collector-emitter voltage	open base		-	-	40	V
I _C	collector current			-	-	200	mA
h _{FE}	DC current gain	V _{CE} = 1 V; I _C = 10 mA		100	180	300	



40 V, 200 mA double NPN switching transistor

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1	$\begin{bmatrix} 1 \\ 7 \end{bmatrix}$	
3	C2	collector TR2	2 5	(TR1) TR2)
4	E2	emitter TR2		
5	B2	base TR2	3 8 4	E1 B1 C2
6	C1	collector TR1		sym020
7	C1	collector TR1	Transparent top view	
8	C2	collector TR2	DFN1412-6 (SOT1268)	

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PMBT3904RA		plastic, thermal enhanced ultra thin small outline package; no leads; 6 terminals; 1.4 mm x 1.2 mm x 0.47 mm body	SOT1268			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMBT3904RA	C6

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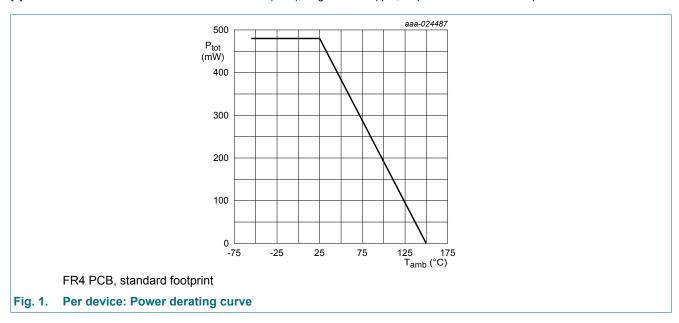
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		•			
V _{CBO}	collector-base voltage	open emitter		-	60	V
V _{CEO}	collector-emitter voltage	open base		-	40	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	200	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	200	mA
I _{BM}	peak base current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	325	mW
Per device			•			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



40 V, 200 mA double NPN switching transistor

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

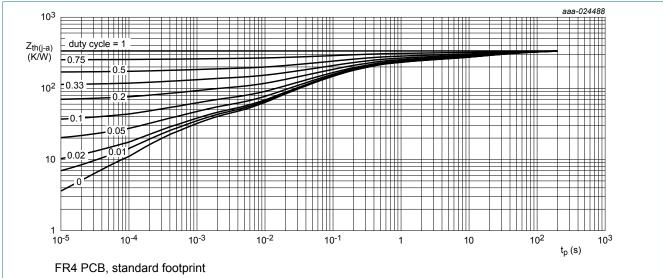


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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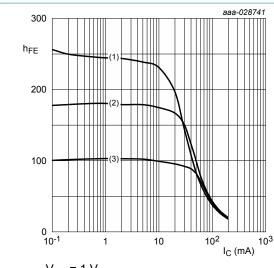
10. Characteristics

Table 7. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A	60	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I _C = 1 mA; I _B = 0 A	40	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I _C = 0 A; I _E = 100 μA	6	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 30 V; I _E = 0 A	-	-	50	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 6 V; I _C = 0 A	-	-	50	nA
h _{FE} DC curre	DC current gain	V _{CE} = 1 V; I _C = 100 μA	60	180	-	
		V _{CE} = 1 V; I _C = 1 mA	80	180	-	
		V _{CE} = 1 V; I _C = 10 mA	100	180	300	
		V _{CE} = 1 V; I _C = 50 mA	60	105	-	
		V_{CE} = 1 V; I_{C} = 100 mA; pulsed; $t_{p} \le$ 300 μs; $\delta \le$ 0.02	30	50	-	
V _{CEsat} collect	collector-emitter	I _C = 10 mA; I _B = 1 mA	-	75	200	mV
	saturation voltage	I _C = 50 mA; I _B = 5 mA	-	120	300	mV
V _{BEsat}	base-emitter saturation	I _C = 10 mA; I _B = 1 mA	650	750	850	mV
	voltage	I _C = 50 mA; I _B = 5 mA	-	850	950	mV
t _d	delay time	I _C = 10 mA; I _{Bon} = 1 mA; I _{Boff} = -1 mA	-	-	35	ns
t _r	rise time		-	-	35	ns
t _{on}	turn-on time		-	-	70	ns
t _s	storage time		-	-	200	ns
t _f	fall time		-	-	50	ns
t _{off}	turn-off time		-	-	250	ns
C _c	collector capacitance	V _{CB} = 5 V; I _E = 0 A; i _e = 0 A; f = 1 MHz	-	-	4	pF
C _e	emitter capacitance	V _{EB} = 0.5 V; I _C = 0 A; i _c = 0 A; f = 1 MHz	-	-	8	pF
f _T	transition frequency	V _{CE} = 20 V; I _C = 10 mA; f = 100 MHz	300	-	-	MHz

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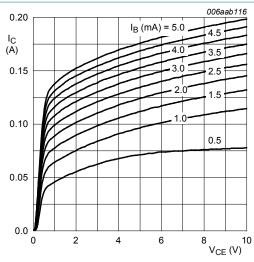


$$V_{CE} = 1 V$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

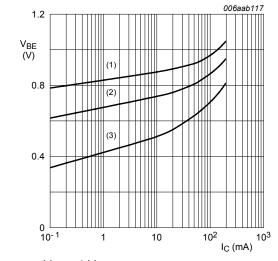
$$(3) T_{amb} = -55 °C$$

Fig. 3. DC current gain as a function of collector current; typical values



 T_{amb} = 25 °C

Fig. 4. Collector current as a function of collectoremitter voltage; typical values



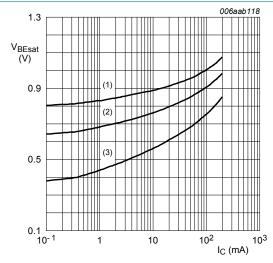
 $V_{CE} = 1 V$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. Base-emitter voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

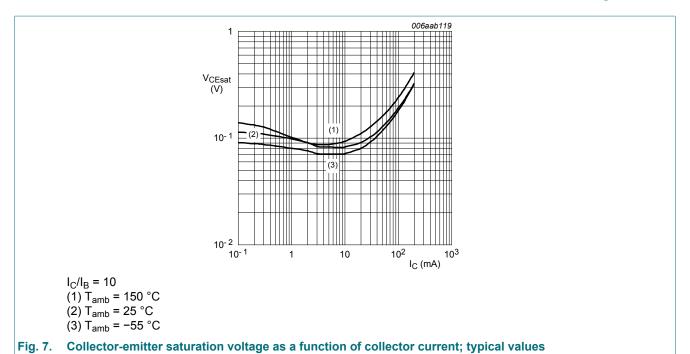
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = 150 °C$$

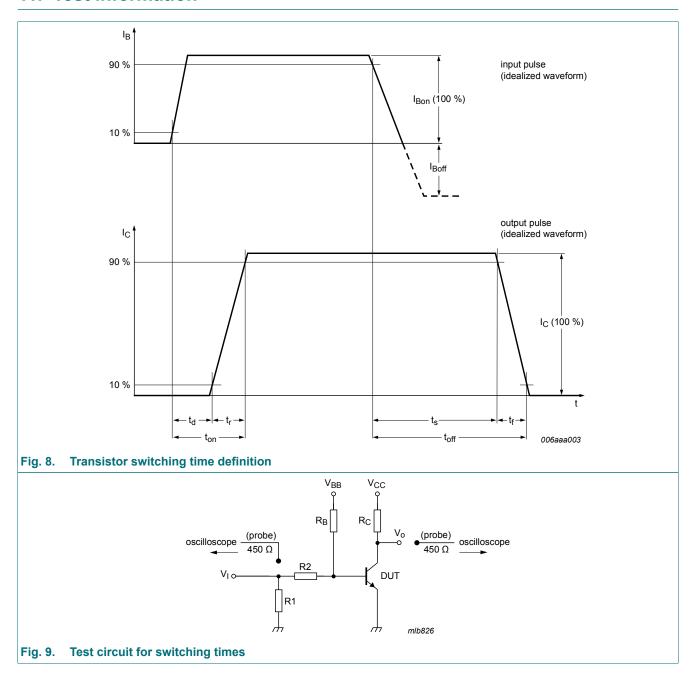
Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values

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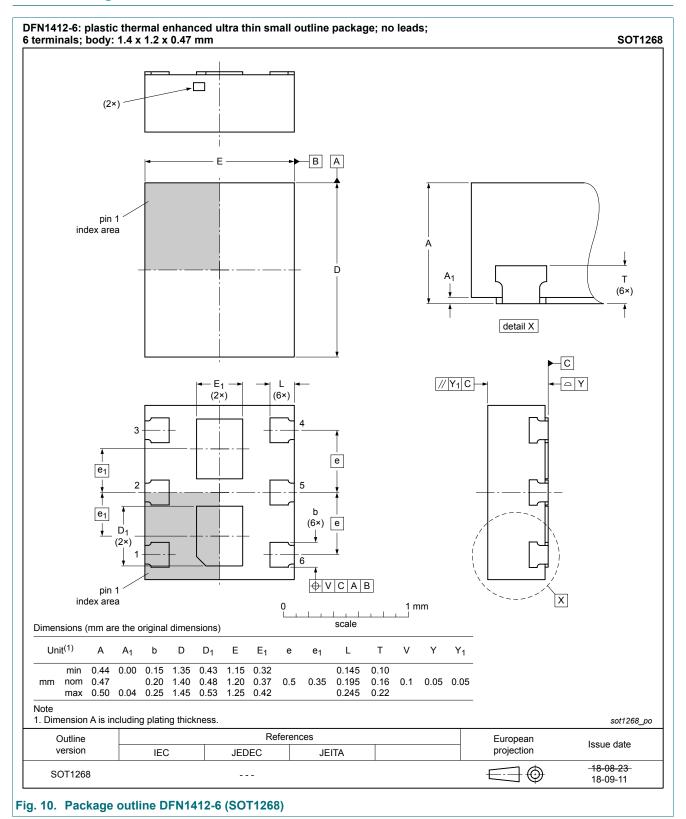
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11. Test information



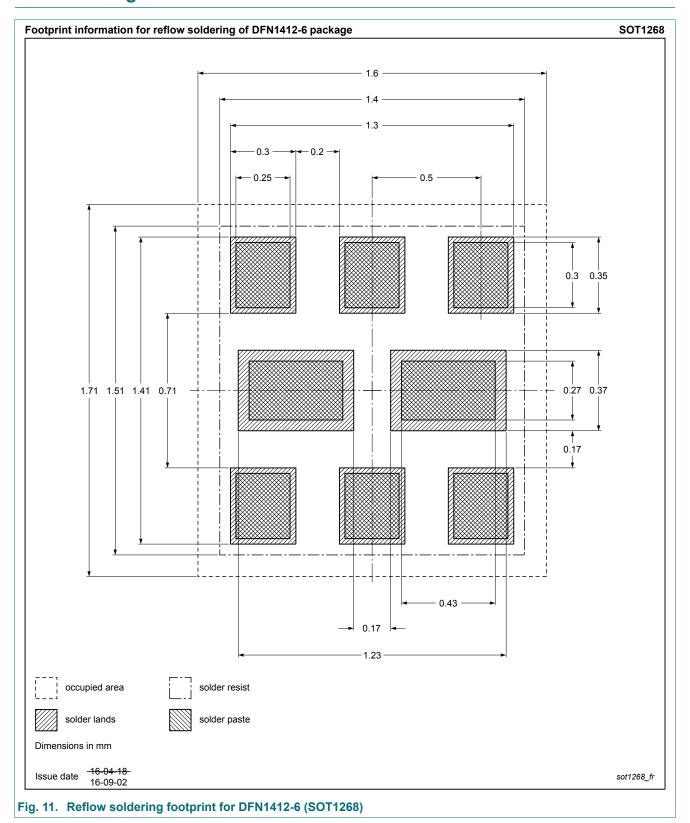
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12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMBT3904RA v.1	20180913	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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